



BAT54x

DIODE

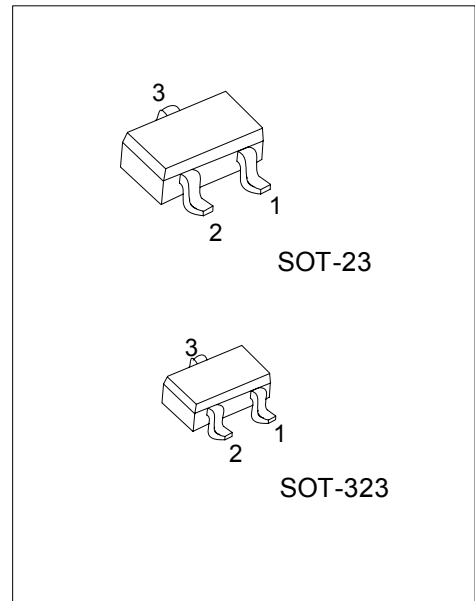
SCHOTTKY BARRIER (DUAL) DIODES

DESCRIPTION

Planar Schottky barrier diodes encapsulated in the SOT-23 and SOT-323 small plastic SMD package. Single diodes and dual diodes with different pin configuration are available.

FEATURES

- * Low forward voltage
- * Guard ring protected
- * Small plastic SMD package



*Pb-free plating product number: BAT54xL

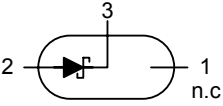
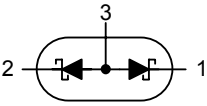
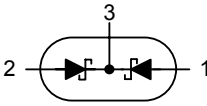
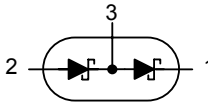
ORDERING INFORMATION

Order Number		Package	Pin Assignment			Packing
Normal	Lead Free Plating		1	2	3	
BAT54-AE3-R	BAT54L-AE3-R	SOT-23	x	A	K	Tape Reel
BAT54A-AE3-R	BAT54AL-AE3-R	SOT-23	K1	K2	A2A1	Tape Reel
BAT54C-AE3-R	BAT54CL-AE3-R	SOT-23	A1	A2	K2K1	Tape Reel
BAT54S-AE3-R	BAT54SL-AE3-R	SOT-23	K1	A2	K2A1	Tape Reel
BAT54-AL3-R	BAT54L-AL3-R	SOT-323	x	A	K	Tape Reel
BAT54A-AL3-R	BAT54AL-AL3-R	SOT-323	K1	K2	A2A1	Tape Reel
BAT54C-AL3-R	BAT54CL-AL3-R	SOT-323	A1	A2	K2K1	Tape Reel
BAT54S-AL3-R	BAT54SL-AL3-R	SOT-323	K1	A2	K2A1	Tape Reel

Note: Pin Assignment: A: Anode K: Cathode x:NC

<p>BAT54L-AE3-R</p>	<p>(1) R: Tape Reel (2) AE3: SOT-23, AL3: SOT-323 (3) L: Lead Free Plating Blank: Pb/Sn</p>
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■ DIODE CONFIGURATION AND SYMBOL

BAT54	BAT54A	BAT54C	BAT54S
			

■ MARKING

BAT54	BAT54A	BAT54C	BAT54S
			

■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT
Per diode			
Continuous Reverse Voltage	V_R	30	V
Continuous Forward Current	I_F	200	mA
Repetitive Peak Forward Current ($t_p < 1s, \leq 0.5$)	I_{FRM}	300	mA
Non-repetitive Peak Forward Current ($t_p < 10ms$)	I_{FSM}	600	mA
Junction Temperature	T_J	+125	
Storage Temperature	T_{STG}	-60 ~ +150	
Per device			
Power Dissipation ($T_a \leq 25$)	P_D	230	mW

Note Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Thermal Resistance From Junction to Ambient	SOT-23	500	K/W
	SOT-323	625	K/W

■ ELECTRICAL CHARACTERISTICS ($T_a = 25$, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Forward Voltage (See Fig.1)	V_F	$I_F = 0.1mA$			240	mV
		$I_F = 1mA$			320	mV
		$I_F = 10mA$			400	mV
		$I_F = 30mA$			500	mV
		$I_F = 100mA$			800	mV
Reverse Current (See Fig.2)	I_R	$V_R = 25V$			2	μA
Reverse Recovery Time (see Fig.4)	t_{rr}	When switched from $I_F = 10mA$ to $I_R = 10mA, R_L = 100\Omega$ measured at $I_R = 1mA$			5	ns
Diode Capacitance (see Fig.3)	C_d	$f = 1 MHz, V_R = 1V;$			10	pF

TYPICAL CHARACTERISTICS

Fig.1 Forward current as a function of forward voltage; typical values.

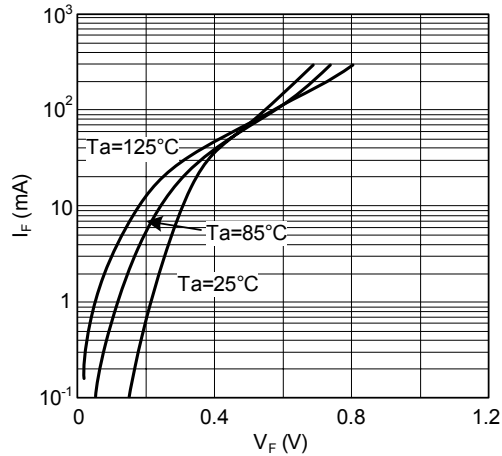


Fig.2 Reverse current as a function of reverse voltage; typical values.

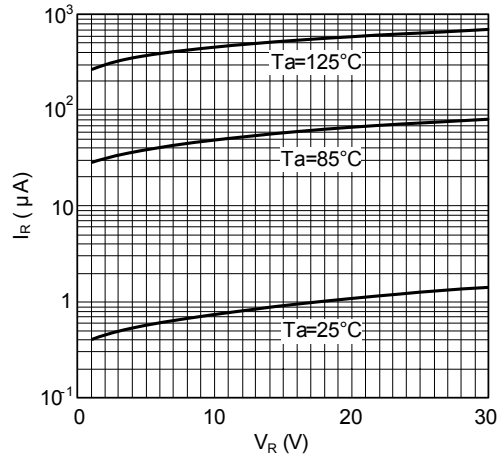


Fig.3 Diode capacitance as a function of reverse voltage; typical values.

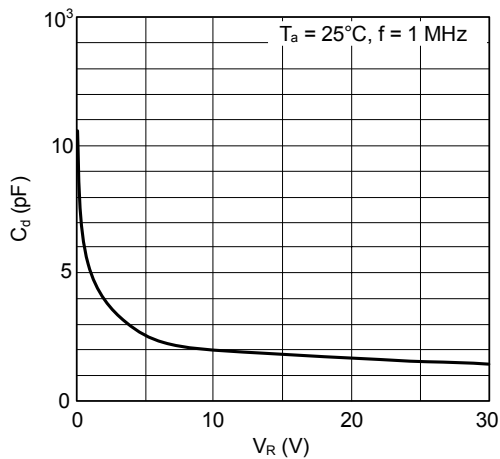
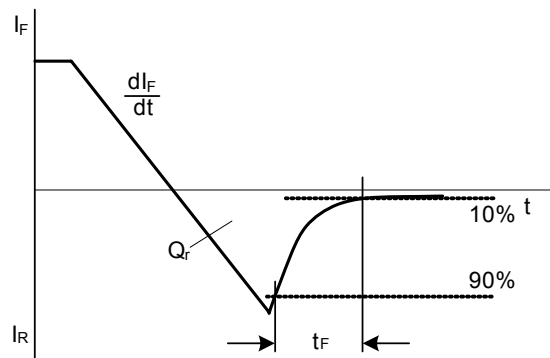


Fig.4 Reverse recovery definitions



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